## 2008 International Symposium on **Semiconductor Manufacturing**

(ISSM 2008)

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## ISSM 2008 Program Schedule

The 1st o	day (Monday,	, October 27)
<b>Tutorial</b>	Session	Room: Century A/B
9:30	Tutorial S	Session AEC/APC
		Introduction of AEC/APC's history
		Mr. Toshihiko Osada, Senior Manager, Fujitsu Microelectronics Limited
		Manufacturing engineering and AEC/APC
		Mr. Kensuke Uriga, CEO/President, Dura Systems Corporation
		Application of control theory for AEC/APC in semiconductor fabrication
		Mr. Hiroshi Shimizu, Director/Advanced Solution Department,
		Advance Automation Company, Yamatake Corporation
9:00	Tutorial S	Session ESH
		SUSTAINABILITY AND ESH ASPECTS OF ADVANCED SEMICONDUCTOR
		MANUFACTURING
		Prof. Farhang Shadman, Regents Professor of Chemical and Environmental Engineering,
		the University of Arizona
Opening	g Remarks	Room: Century
13:00		
Keynote	Speech Sess	ion Room: Century
13:20		Challenges in The DRAM Business
		Mr.Yukio Sakamoto, President&CEO, Elpida Memory,Inc.
14:10		The New Dynamics of Semiconductor Industry
		Dr. Tien Wu, Chief Operating Officer, Board of Directors, Advanced Semiconductor
		Engineering Inc.(ASE)
15:00		Break
Oral Ses	ssion	Room: Century A
Highligh	nt Session <ac< td=""><td>dvanced Lithography Session&gt;</td></ac<>	dvanced Lithography Session>
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		Benjamin Bunday, ISMI
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		Patterning Defectitivity11
		Amiad Conley, Applied Materials
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16:30	PO-O-040	Defect Reduction in ArF Immersion Lithography, Using Particle Trap Wafers with
		CVD Thin Films
		Yoshinori Matsui, NEC Electronics
16:50	PO-O-154	Defectivity readiness for immersion scanner qualification towards 32nm
<b>-</b>	· · ·	production
		Ofer Rotlevi, Applied Materials
17:10	UC-O-110	Defect Reducton in Advanced Lithography Processes Using a New Dual
	0000	Functionality Filter
		Aiwen Wu, Entegris
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		Kazuya Dobashi, Tokyo Electron			
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		Kazunori Imaoka, Spansion			
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		Yea-Huey Su, National Central University			
17:10	MS-O-202	Method and System for Determining Optimal Wafer Sampling in	n Realtime Inline		
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		Kari Johnson, Micron Technology			
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18:30		ISSM Reception	Room: Century		
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9:00		Manufacturing Challenges in Automotive Nanoelectronics  Dr. Reinhard Ploss, Member of the Management Board Operations, Infineon Technologies AG				
9:50		Heterogeneous Integration and Clustered Virtual Vertical Integration for IC Industry Dr. Nicky C. C. Lu, Chairman/CEO, Etron Technology, Inc.				
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The 2 <sup>nd</sup> day	(Tuesday,	October 28)	
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